Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type

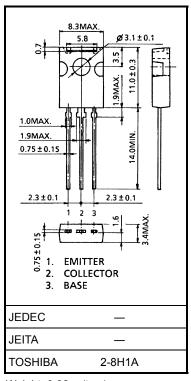
# 2SC5368

High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- High speed:  $t_r = 0.5 \mu s$  (max),  $t_f = 0.3 \mu s$  (max) ( $I_C = 0.8 A$ )
- High breakdown voltage:  $V_{CEO} = 450 \text{ V}$
- High DC current gain:  $h_{FE} = 20$  (min) ( $I_{C} = 0.2$  A)

### **Absolute Maximum Ratings (Tc = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	650	V	
Collector-emitter voltage		V <sub>CEO</sub>	450	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	I <sub>C</sub>	2	А	
	Pulse	I <sub>CP</sub>	4		
Base current		I <sub>B</sub>	0.5	Α	
Collector power dissipation	Ta = 25°C	P <sub>C</sub>	1.5	W	
	Tc = 25°C	FC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 0.82 g (typ.)

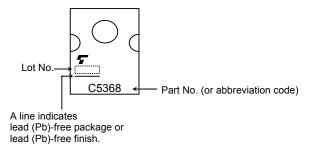
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

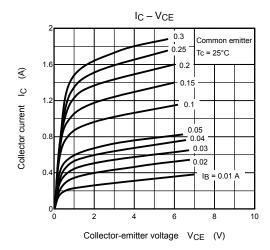
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

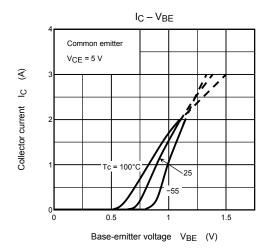
## **Electrical Characteristics (Tc = 25°C)**

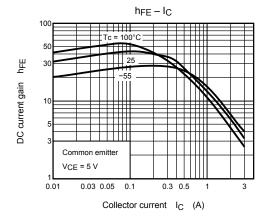
Chara	Characteristics Symbol Test Condition		Min	Тур.	Max	Unit	
Collector cut-off of	current	I <sub>CBO</sub>	V <sub>CB</sub> = 520 V, I <sub>E</sub> = 0	_	_	20	μΑ
Emitter cut-off cu	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	_	10	μΑ
Collector-base breakdown voltage		V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0	650	_	_	V
Collector-emitter	breakdown voltage	V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	450	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	13	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.2 A	20	_	65	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 0.8 A, I <sub>B</sub> = 0.1 A	_	_	1.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 0.8 A, I <sub>B</sub> = 0.1 A	_	_	1.3	V
Switching time S	Rise time	t <sub>r</sub>	V <sub>CC</sub> ≈ 200 V 20 μs	_	_	0.5	
	Storage time	t <sub>stg</sub>	INPUT IB2	I	_	2.0	μs
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = 0.1 A, I <sub>B2</sub> = −0.2 A, Duty cycle ≤ 1%	_	_	0.3	

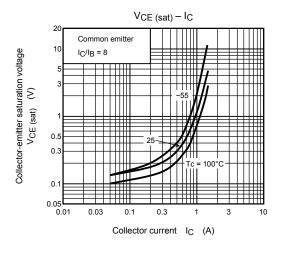
## Marking

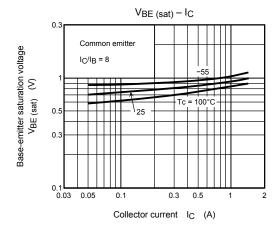


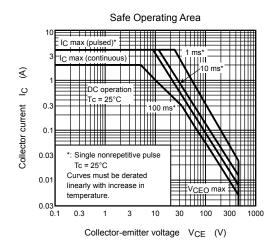












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